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**Serial Number: 09/557,289**

with Lateral Oxidation Barrier,” issued on July 31, 2001, which is a divisional application of Patent Application No. 09/235,639, entitled “Conductive Element with Lateral Oxidation Barrier,” filed on January 22, 1999, now U.S. Patent No. 6,014,395, entitled “Oxidizable Semiconductor Device Having Cavities Which Allow for Improved Oxidation of the Semiconductor Device,” issued on January 11, 2000, which is a divisional application of Patent Application No. 08/986,401, entitled “Conductive Element with Lateral Oxidation Barrier,” filed on December 8, 1997, now U.S. Patent No. 5,093,589, entitled, “Oxidizable Semiconductor Device Having Cavities Which Allow for Improved Oxidation of the Semiconductor Device,” issued on May 11, 1999, and Patent Application No. 08/964,598, entitled, “Conductive Element with Lateral Oxidation Barrier,” filed on November 5, 1997, now U.S. Patent No. 5,897,329, entitled, “Method for Producing an Electrically Conductive Element for Semiconductor Light Emitting Devices,” issued on April 27, 1999, which are divisional applications of Patent Application 08/574,165, entitled “Conductive Element with Lateral Oxidation Barrier,” filed on December 18, 1995, now U.S. Patent No. 5,719,891, entitled, “Conductive Element with Lateral Oxidation Barrier,” issued on February 17, 1998. The entire disclosure and contents of the above patents and applications are hereby incorporated by reference.

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